Constantes

$$\begin{split} k_B &= 1.381 \times 10^{-23} J K^{-1} = 8.26 \times 10^{-5} eV K^{-1} \\ m_e &= 9.11 \times 10^{-31} kg = 0.511 MeV c^{-2} \\ m_p &= 1.67 \times 10^{-27} kg = 938 MeV c^{-2} \\ \varepsilon_0 &= \frac{1}{4\pi K} = 8.85 \times 10^{-12} Fm^{-1} \\ \hbar &= 1.055 \times 10^{-34} Js = 6.58 \times 10^{-16} eVs \\ e &= 1.602 \times 10^{-19} C \end{split}$$
 Fermions: $e^-, p, n \quad (n_F(E) = \frac{1}{e^{\beta E} + 1})$

Bosons: phonon, photon $(n_B(E) = \frac{1}{e^{\beta E} - 1})$ $n \sim 10^{22} cm^{-3}; \tau \sim 10^{-15} s; v \sim 10^{-5} \frac{m}{s}$

1 Estructura cristalina

1.1 Redes de Bravais

	a	triclínica
	m	monoclínica
ſ	0	ortorómbica
ſ	t	tetragonal
Ī	h	hexagonal
Ī	c	cúbica

P	Primitiva
S	Centrada en una cara
I	Centrada en el cuerpo
R	Centrada romboidal
F	Centrada en las caras

14 posibles redes de Bravais

	_	_	_	
Condiciones	de	Laue	Q	$=2\pi \overline{q}_{hh}$

Ley de Bragg $g_{hkl} = \frac{2\sin\theta_{hkl}}{\lambda}$

Módulo de Young $\nu_s = \sqrt{\frac{\gamma}{\rho}}$

Factor de estructura $F_{hkl}=\sum_p f_p e^{-i2\pi \overline{g}_{hkl}\cdot \overline{r}_p}; I\propto |F_{hkl}|^2$

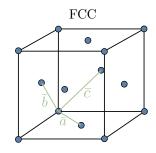
1.3 Estructuras comunes

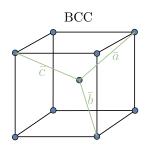
FCC (primitiva volumen 1/4)

$$\begin{cases} \overline{a} = \frac{1}{2}(1 \ 1 \ 0) \\ \overline{b} = \frac{1}{2}(0 \ 1 \ 1) \\ \overline{c} = \frac{1}{2}(1 \ 0 \ 1) \end{cases} \qquad \begin{cases} \overline{a}^* = (1 \ 1 \ -1) \\ \overline{b}^* = (-1 \ 1 \ 1) \\ \overline{c}^* = (1 \ -1 \ 1) \end{cases}$$

BCC (primitiva volumen 1/2)

$$\begin{cases} \overline{a} = \frac{1}{2}(1 \ 1 \ -1) \\ \overline{b} = \frac{1}{2}(-1 \ 1 \ 1) \\ \overline{c} = \frac{1}{2}(1 \ -1 \ 1) \end{cases} \qquad \begin{cases} \overline{a}^* = (1 \ 1 \ 0) \\ \overline{b}^* = (0 \ 1 \ 1) \\ \overline{c}^* = (1 \ 0 \ 1) \end{cases}$$





					Ц	ze con el
Tric.	Monoc.	Ortor.	Tetra.	Hex.	Cúbico	xagonal
aP	mP, mS	oP, oS, oF, oI	tP, tI	hP, hR	cP, cF, cI	(-

$$\begin{cases} \overline{a} = (1,0) \\ \overline{b} = (-\frac{1}{2}, \frac{\sqrt{3}}{2}) \end{cases} \begin{cases} \overline{a}^* = \frac{2\sqrt{3}}{3} (\frac{\sqrt{3}}{2}, \frac{1}{2}) \\ \overline{b}^* = \frac{2\sqrt{3}}{3} (0,1) \end{cases}$$

Dago dual u matria mátrias

Cosas

Base dual y matriz métrica

$$a^* = \frac{b \times c}{V}, \quad b^* = \frac{c \times a}{V}, \quad c^* = \frac{a \times b}{V}, \quad V = \det(\overline{a}, \overline{b}, \overline{c})$$
$$(\overline{a}^*, \overline{b}^*, \overline{c}^*) = \begin{pmatrix} \overline{a}^T \\ \overline{b}^T \\ \overline{c}^T \end{pmatrix}^{-1}, G = \begin{pmatrix} a \cdot a & a \cdot b & a \cdot c \\ b \cdot a & b \cdot b & b \cdot c \\ c \cdot a & c \cdot b & c \cdot c \end{pmatrix}, G^* = G^{-1}$$

Cambio de base

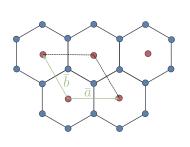
1.2

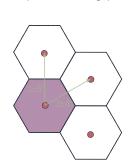
$$(\overline{a}', \overline{b}', \overline{c}') = (\overline{a}, \overline{b}, \overline{c})P, \quad \begin{pmatrix} x' \\ y' \\ z' \end{pmatrix} = P^{-1} \begin{pmatrix} x \\ y \\ z \end{pmatrix}$$
$$(x, y, z) = (x^*, y^*, z^*)P, \quad \begin{pmatrix} a'^* \\ b'^* \\ z'^* \end{pmatrix} = P^{-1} \begin{pmatrix} a^* \\ b^* \\ c^* \end{pmatrix}$$

Distancia interplanar $g_{hkl} = \frac{2}{d_{hkl}}; \quad g_{hkl}^2 = (hkl)G^* \begin{pmatrix} h \\ k \\ l \end{pmatrix}$

Transferencia de momento $Q = \frac{4\pi \sin \theta}{\lambda}$

$$G = \begin{pmatrix} a^2 & -\frac{a^2}{2} & 0\\ -\frac{a^2}{2} & a^2 & 0\\ 0 & 0 & 2 \end{pmatrix}, \quad G^* = \begin{pmatrix} \frac{4}{3g^2} & \frac{2}{3q^2} & 0\\ \frac{3a^2}{3a^2} & \frac{3a^2}{3a^2} & 0\\ 0 & 0 & 1 \end{pmatrix}$$





En una hcp c = 1.633a

1.4 Grupos

$$m_{100} = \begin{pmatrix} -1 & 0 & 0 \\ 0 & 1 & 0 \\ 0 & 0 & 1 \end{pmatrix}; n_{001} = \begin{pmatrix} \cos\left(\frac{360}{n}\right) & -\sin\left(\frac{360}{n}\right) & 0 \\ \sin\left(\frac{360}{n}\right) & \cos\left(\frac{360}{n}\right) & 0 \\ 0 & 0 & 1 \end{pmatrix}$$

Cambio de base a $\mathcal{B} = \{\overline{u}, \overline{v}, \overline{w}\}$

$$M_{\mathcal{C}} = M_{\mathcal{B} \to \mathcal{C}} M_{\mathcal{B}} M_{\mathcal{B} \to \mathcal{C}}^{-1}, \quad M_{\mathcal{B} \to \mathcal{C}} = (\overline{u}, \overline{v}, \overline{w})$$

Reflexión vector director (a, b, c)

$$M = \frac{1}{a^2 + b^2 + c^2} \begin{pmatrix} -a^2 + b^2 + c^2 & -2ab & -2ac \\ -2ab & a^2 - b^2 + c^2 & -2bc \\ -2ac & -2bc & a^2 + b^2 - c^2 \end{pmatrix} \omega_{\pm}(k) = \sqrt{\frac{k_1 + k_2}{m} \pm \frac{1}{m} \sqrt{(k_1 + k_2)^2 - 4k_1k_2\sin^2(ka/2)}}$$
 So where $m_1 \neq m_2$ is $m_1 \neq m_2$ in $m_2 \neq m_3$ in $m_4 \neq m_4$ in m

Rotación respecto $\hat{u} = (u_x, u_y, u_z)$ $(c = \cos \theta, s = \sin \theta)$

$$\begin{pmatrix} c + u_x^2(1-c) & u_x u_y(1-c) - u_z s & u_x u_z(1-c) + u_y s \\ u_y u_x(1-c) + u_z s & c + u_y^2(1-c) & u_y u_z(1-c) - u_x s \\ u_z u_x(1-c) - u_y s & u_z u_y(1-c) + u_x s & c + u_z^2(1-c) \end{pmatrix}$$

Centrosimétricos $(x, y, z) \rightarrow (-x, -y, -z)$ no tienen polarización espontánea

2 Dinámica de cristales

2.1Densidad de estados

$$\overline{k} = \begin{pmatrix} \frac{2\pi}{L} n & \frac{2\pi}{L} m & \frac{2\pi}{L} l \end{pmatrix} \ \forall n, m, l \in \mathbb{Z}$$

Número de estados hasta k

$$N(k) = \int_{(\frac{2\pi}{L})^2(n^2 + m^2 + l^2) \le k^2} dV = \frac{L^3}{6\pi^2} k^3 = \frac{V}{6\pi^2} k^3$$

1, 2 y 3 dimensiones respectivamente (y se cumple $\omega = \nu_s k$)

$$\begin{cases} g(k) = \frac{L}{\pi} \\ g(\omega) = \frac{L}{\pi\nu} \end{cases} \begin{cases} g(k) = \frac{L^2}{2\pi}k \\ g(\omega) = \frac{L}{2\pi\nu^2}\omega \end{cases} \begin{cases} g(k) = \frac{V}{2\pi^2}k^2 \\ g(\omega) = \frac{V}{2\pi^2\nu_s^3}\omega^2 \end{cases}$$

2.2Dispersión

Oscilador con masa m y constante k_s

$$F_n = m\ddot{x}_n = k_s(x_{n+1} + x_{n-1} - 2x_n)$$

$$-m\omega^2 A e^{i(kna-\omega t)} = k_s A e^{i(kna-\omega t)} (e^{ika} + e^{-ika} - 2) =$$

$$= -4k_s \sin^2\left(\frac{ka}{2}\right) \Rightarrow \left[\omega = 2\sqrt{\frac{k_s}{m}} \left|\sin\left(\frac{ka}{2}\right)\right|\right]$$

Oscilador con masa m y constantes alternadas k_1, k_2

$$\begin{cases}
m\ddot{x}_n = k_1(y_{n-1} - x_n) + k_2(y_n - x_n) \\
m\ddot{y}_n = k_1(x_{n+1} - y_n) + k_2(x_n - y_n)
\end{cases}$$

Ansatz

$$x_n = Ae^{i(kna - \omega t)}$$
 $y_n = Be^{i(kna - \omega t)}$

Ecuaciones

$$\begin{cases}
-m\omega^2 A = -A(k_1 + k_2) + B(k_1 e^{ika} + k_2) \\
-m\omega^2 B = -A(k_1 e^{ika} + k_2) + B(-k_1 - k_2)
\end{cases}$$

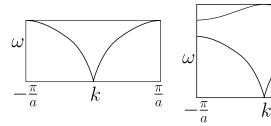
$$m\omega^2 \begin{pmatrix} A \\ B \end{pmatrix} = \begin{pmatrix} (k_1 + k_2) & -k_2 - k_1 e^{ika} \\ -k_2 - k_1 e^{ika} & (k_1 + k_2) \end{pmatrix} \begin{pmatrix} A \\ B \end{pmatrix} = K \begin{pmatrix} A \\ B \end{pmatrix}$$

$$0 = \det(K - m\omega^2 I) = |(k_1 + k_2) - m\omega^2|^2 - |k_2 + k_1 e^{ika}|^2$$

$$\omega_{\pm}(k) = \sqrt{\frac{k_1 + k_2}{m} \pm \frac{1}{m} \sqrt{(k_1 + k_2)^2 - 4k_1 k_2 \sin^2(ka/2)}}$$

$$\omega_{\pm}(k) = \sqrt{(K_1 + K_2) \pm \sqrt{(K_1 + K_2)^2 - 4K_1K_2\sin^2(ka/2)}}$$

 π



Si hay N átomos / celda: 3N ramas:

- 3 acústicas (2 trans. < 1 long.)
- 3N 3 ópticas

2.3 Modelo de Einstein

$$E_n = \hbar\omega(n + \frac{1}{2}) \quad \Rightarrow \quad Z_1 = \frac{1}{2\sinh(\frac{\beta\hbar\omega}{2})}$$
$$\langle E_1 \rangle = -\frac{\partial}{\partial\beta}\ln Z_1 = \frac{\hbar\omega}{2}\coth\left(\frac{\beta\hbar\omega}{2}\right)$$

Energía y capacidad calorífica

$$\langle E \rangle = \frac{3}{2} N \hbar \omega \coth\left(\frac{\beta \hbar \omega}{2}\right)$$

$$C_v = \frac{\partial \langle E \rangle}{\partial T} = 3N k_B (\beta \hbar \omega)^2 \frac{e^{\beta \hbar \omega}}{(e^{\beta \hbar \omega} - 1)^2}$$

Definimos ahora $T_E = \frac{\hbar \omega_E}{k_B}$. En los límites

- Si $T \gg T_E$ \Rightarrow $C_v = 3Nk_b$ Si $T \ll T_E$ \Rightarrow $C_v = 3Nk_b(\frac{T_E}{T})^2 \frac{1}{\sinh^2(\frac{T_E}{\sqrt{R_T}})}$

2.4Modelo de Debye

Aproximamos la ecuación de dispersión para k baja como $\omega = \nu k$

$$3N = \int_0^{\omega_D} 3g(\omega) d\omega = \frac{V}{2\pi^2 \nu^3} \omega_D^3 \Rightarrow \boxed{\omega_D = \sqrt[3]{\frac{6\pi^2 \nu^3 N}{V}}}$$

donde hemos contado cada partícula y cada estado 3 veces y hemos usado

$$\omega = \nu k, \qquad g(k) = \frac{V}{2\pi^2} k^2, \qquad g(\omega) = \frac{V}{2\pi^2 \nu^3} \omega^2$$

La energía y la capacidad calorífica

$$\begin{split} \langle E \rangle &= \int_0^{\omega_D} \hbar \omega 3 g(\omega) \left(\frac{1}{e^{\beta \hbar \omega} - 1} + \frac{1}{2} \right) d\omega = \\ &= E_0 + \frac{3V\hbar}{2\pi^2 \nu^3} \int_0^{\omega_D} \frac{\hbar \omega^3}{e^{\beta \hbar \omega} - 1} d\omega \qquad (x = \frac{\hbar \omega}{k_B T}) \end{split}$$

$$T_D := \frac{\hbar\omega}{k_B} \quad \Rightarrow \left| \langle E \rangle = \frac{3V k_B^4 T^4}{2\pi^2 \nu^3 \hbar^3} \int_0^{\frac{T_D}{T}} \frac{x^3}{e^x - 1} dx \right|$$

La capacidad calorífica $C_v = \frac{\partial \langle E \rangle}{\partial T}$ en los extremos:

- Si $T\gg T_D$ \Rightarrow $\langle E\rangle\sim 3Nk_BT$ \Rightarrow $C_v\sim 3Nk_B$
- Si $T \ll T_D \Rightarrow \langle E \rangle \sim \frac{3\pi^4 N k_B T^4}{5T_D^3} \Rightarrow C_v \sim \frac{12\pi^4}{5} N k_B \left(\frac{T}{T_D}\right)^3$

3 No se, cuanticocosas

3.1 Drude model

$$n = \frac{N}{V}; \quad \frac{dp}{dt} = -\frac{p}{\tau} + F; \quad \overline{j} = -ne\overline{v} = \sigma \overline{E}$$

$$\sigma_0 = \frac{e^2 \tau n}{m}; \quad \text{si } F - e\text{Re}[E_0 e^{i\omega t}] \Rightarrow \sigma(\omega) = \frac{\sigma_0}{1 - i\omega t}$$

$$mv = p = -e\tau E; \quad R_H = \frac{-1}{ne} = \frac{\rho_{yx}}{|B|}$$

$$\overline{E} = \tilde{\rho}\overline{j}; \quad \rho_{xx} = \rho_{yy} = \rho_{zz} \frac{m}{ne^2 \tau}; \quad \frac{1}{2} mv_0^2 = \frac{3}{2} k_B T$$

(COSAS DEL EFECTO HALL PROBLEMA 4)

Hall resistivity $\rho_{xy} = -\rho_{yx} = \frac{B}{ne} \ (\overline{B} \propto \hat{z})$

Peltier coefficient $\Pi = -\frac{k_B T}{2e} = \frac{-c_v T}{3e}$

Seebeck coefficient $S = \frac{\Pi}{T}$

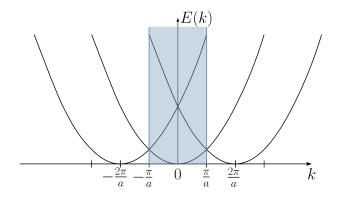
$$\langle v \rangle_{gasid.} = \sqrt{\frac{8k_BT}{\pi m}}; \quad \kappa = \frac{1}{3}nc \langle v \rangle^2 \tau = \frac{4}{\pi} \frac{n\tau k_B^2T}{m}$$

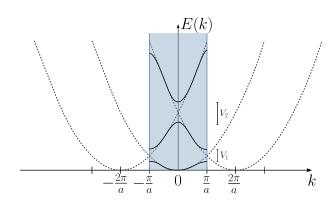
3.2 Capacidad calorífica

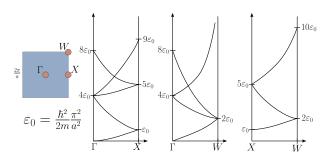
 $g = \frac{\text{densidad de estados}}{V}$

$$\begin{split} g(\varepsilon) &= \frac{3n}{2(E_F)^{\frac{3}{2}}} \varepsilon^{\frac{1}{2}} = \frac{(2m)^{\frac{3}{2}}}{2\pi^2\hbar^3} \varepsilon^{\frac{1}{2}}, \quad k = \sqrt{\frac{2\varepsilon m}{\hbar^2}} \\ N &= \int_0^\infty \!\! d\varepsilon g(\varepsilon) n_F(\beta(\varepsilon-\mu)), \quad E_T = \int_0^\infty \!\! d\varepsilon \varepsilon g(\varepsilon) n_F(\beta(\varepsilon-\mu)) \\ C &= \frac{\pi^2}{3} \left(\frac{3Nk_B}{2}\right) \left(\frac{T}{T_F}\right) \end{split}$$

$$\overline{M} = g(E_F)\mu_B^2 \overline{B}; \quad \mu_B = 0.67 \left(\frac{K}{Tesla}\right) k_B$$







Teorema de Bloch $(V(\overline{r}) \text{ periódico})$

$$\psi_{\overline{k}}(\overline{r}) = u_{\overline{k}}(\overline{r})e^{i\overline{k}\cdot\overline{r}}, \quad E(\overline{k}) = E(\overline{k} + \overline{G})$$

(1D) Fourier del potencial de dos formas

$$V(x) = V_0 + \sum_{j=1}^{\infty} V_j \cos\left(\frac{2\pi j}{a}x\right) \quad \text{ ó } \quad V(x) = \sum_{j=-\infty}^{\infty} V_{\frac{2\pi j}{a}} e^{i\frac{2\pi j}{a}x}$$

Con las relaciones $V_j = 2V_{\frac{2\pi j}{d}},$ y donde los coeficientes son

$$V_{j} = \frac{2}{a} \int_{-\frac{a}{2}}^{\frac{a}{2}} dx V(x) \cos\left(\frac{2\pi j}{a}x\right); \quad V_{\frac{2\pi j}{a}} = \frac{1}{a} \int_{-\frac{a}{2}}^{\frac{a}{2}} dx V(x) e^{-i\frac{2\pi j}{a}x}$$

Gas de electrones libres

$$\overline{k} = \frac{2\pi}{L}(n_x, n_y, n_z), \quad E(\overline{k}) = \frac{\hbar^2}{2m} |\overline{k}|^2, \quad n_F(x) = \frac{1}{e^x + 1}$$

$$N = 2\sum_{\overline{k}} n_F(\beta(E(\overline{k}) - \mu)) = 2\frac{V}{(2\pi)^3} \int d\overline{k} n_F(\beta(E(\overline{k}) - \mu))$$

Fermi energy $(E_F = \mu(T \to 0))$ (d numero de dimensiones)

$$\varepsilon_{F} = \frac{\hbar^{2} k_{F}^{2}}{2m} = k_{B} T_{F}; \quad p_{F} = \hbar k_{F}; \quad U_{T} = \frac{3}{5} \varepsilon_{F} N$$

$$N = 2 \frac{V}{(2\pi)^{d}} \int_{|k| < k_{F}} dk \Rightarrow k_{F} = (3\pi^{2} n)^{\frac{1}{3}}, \quad \varepsilon_{F} = \frac{\hbar^{2} (3\pi^{2} n)^{\frac{2}{3}}}{2m}$$

Considerando los dos espines (multiplicamos por 2)

$$N_T = 2 \cdot \left(\frac{4}{3}\pi (n_x^2 + n_y^2 + n_z^2)^{3/2}\right) \quad \Rightarrow \quad k_{max}^2 = k_F^2 = (3n\pi^2)^{\frac{2}{3}}$$

Electrones casi-libres

$$\psi_{+} \sim \cos(\pi \frac{x}{a}), \quad \psi_{-} \sim \sin(\pi \frac{x}{a})$$

$$E^{\pm} = \frac{1}{2} (E_{\overline{k}-\overline{G}}^{0} + E_{\overline{k}}^{0}) \pm \sqrt{\frac{1}{4} (E_{\overline{k}-\overline{G}}^{0} - E_{\overline{k}}^{0})^{2} + |V_{\overline{G}}|^{2}}$$

Enlace fuerte, celda primitiva cúbica $(B = \gamma, A = \beta)$

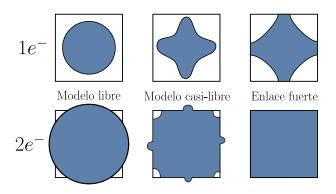
$$\begin{split} E(\overline{k}) &\approx E_i - A - 2B(\cos k_x a + \cos k_y a + \cos k_z a) \\ A &= -\langle \varphi_{i,n} | v | \varphi_{i,n} \rangle, \quad B = -\langle \varphi_{i,m} | v | \varphi_{i,n} \rangle \\ \overline{v} &= \nabla_{\overline{k}} \omega(\overline{k}) = \frac{1}{\hbar} \nabla_{\overline{k}} E(\overline{k}) \end{split}$$

Carga de un campo $\overline{\mathcal{E}}$

$$\dot{v}_i = \frac{1}{\hbar^2} \sum_j \frac{\partial^2 E}{\partial k_i \partial k_j} (-e \mathcal{E}_j), \quad \left(\frac{1}{m^*}\right)_{ij} = \frac{1}{\hbar^2} \frac{\partial^2 E(\bar{k})}{\partial k_i \partial k_j}$$

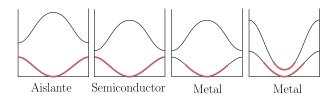
Caso totalmente degenerado

$$m^* = \frac{\hbar^2}{\left(\frac{d^2 E}{dk^2}\right)}, \quad E(\overline{k}) = E_0 + \frac{\hbar^2}{2m^*}|k|^2, \quad \sigma \simeq \frac{e^2 \tau(E_F)n}{m^*}$$



Tipos de materiales

Aislante: Banda llena $(2e^-)$. $V_g > 4eV$ Semiconductor Banda llena $(2e^-)$. $V_g < 4eV$. Metal Banda semillena $(1e^2 \circ 2e^- \text{ con bandas solapantes})$.



4 Semiconductores

extrínseco = dopado Opacos si $h\nu > E_g$ Nivel de Fermi $E_F = \mu$ Densidad de estados (n electrones, p holes)

$$\begin{split} g_C(\varepsilon) &= \frac{(2m_n^*)^{2/3}}{2\pi^2\hbar^3} \sqrt{\varepsilon - \varepsilon_C}; g_V(\varepsilon) = \frac{(2m_p^*)^{2/3}}{2\pi^2\hbar^3} \sqrt{\varepsilon_V - \varepsilon} \\ n &= \frac{1}{4} \left(\frac{2m_n^*k_BT}{\pi\hbar^2}\right)^{3/2} e^{\beta(\mu - \varepsilon_C)} = N_{eff}^C e^{\beta(\mu - \varepsilon_C)} \\ p &= \frac{1}{4} \left(\frac{2m_p^*k_BT}{\pi\hbar^2}\right)^{3/2} e^{\beta(\varepsilon_V - \mu)} = N_{eff}^V e^{\beta(\varepsilon_V - \mu)} \\ np &= N_{eff}^C N_{eff}^V e^{-\beta E_g} = 4 \left(\frac{k_BT}{2\pi\hbar^2}\right)^3 (m_n^*m_p^*)^{3/2} e^{-\beta E_g} \\ e^{2\beta\mu} &= \frac{N_{eff}^V}{N_{eff}^C} e^{\beta(\varepsilon_V + \varepsilon_C)}, \quad \mu = \frac{\varepsilon_C + \varepsilon_V}{2} + \frac{3}{4} k_B T \ln\left(\frac{m_p^*}{m_n^*}\right) \\ \mu &= \frac{e\tau}{m^*}, \quad \sigma = e(n\mu_n + p\mu_p), \quad E_g = \varepsilon_C - \varepsilon_V \\ n &= p = \sqrt{N_{eff}^C N_{eff}^V} e^{-\frac{\beta E_g}{2}} \quad \text{si intrinseco} \end{split}$$

Semiconductores dopados (n=1 ionización) $\varepsilon = \varepsilon_0 \varepsilon_r$

$$E_{n} = \frac{m^{*}e^{4}}{2(4\pi\varepsilon\hbar)^{2}} \frac{1}{n^{2}}, \quad r_{n} = \varepsilon \frac{4\pi\hbar^{2}}{m^{*}e^{2}} n^{2}$$

$$n \approx \frac{2N_{D}}{1 + \sqrt{1 + 4\frac{N_{D}}{N_{eff}^{C}}} e^{\beta E_{d}}}$$

Unión p-n

$$\begin{split} n_n &= N_{eff}^C e^{\beta(\mu - \varepsilon_C^n)}; \quad p_p = N_{eff}^V e^{\beta(\varepsilon_V^p - \mu)} \\ d_n^0 &= \sqrt{\frac{2\varepsilon V_D}{e} \frac{N_A/N_D}{N_A + N_D}}; \quad d_p^0 = \sqrt{\frac{2\varepsilon V_D}{e} \frac{N_D/N_A}{N_A + N_D}} \\ d_n(U) &= d_n^0 \sqrt{1 - \frac{U}{V_D}}; \quad d_p(U) = d_p^0 \sqrt{1 - \frac{U}{V_D}} \\ eV_D &= k_B T \ln \left(\frac{n_n p_p}{n_s^2}\right); \quad I(U) = (I_n^{gen} + I_p^{gen})(e^{\beta e U} - 1) \end{split}$$

5 Mates

$$\sin^{2}\left(\frac{x}{2}\right) = \frac{1-\cos a}{2}$$

$$\int_{0}^{\infty} \frac{1}{e^{x}-1} dx = +\infty, \quad \int_{0}^{\infty} \frac{1}{e^{x}+1} dx = \ln(2)$$

$$\int_{0}^{\infty} \frac{x}{e^{x}-1} dx = \frac{\pi^{2}}{6}, \quad \int_{0}^{\infty} \frac{x}{e^{x}+1} dx = \frac{\pi^{2}}{12}$$

$$\int_{0}^{\infty} \frac{x^{2}}{e^{x}-1} dx = 2\zeta(3), \quad \int_{0}^{\infty} \frac{x^{2}}{e^{x}+1} dx = \frac{3}{2}\zeta(3)$$

$$\int_{0}^{\infty} \frac{x^{3}}{e^{x}-1} dx = \frac{\pi^{4}}{15}, \quad \int_{0}^{\infty} \frac{x^{3}}{e^{x}+1} dx = \frac{7\pi^{4}}{120}$$